

C0201C270K8GACTU

Aliases (C0201C270K8GAC7867) SMD Comm COG, Ceramic, 27 pF, 10%, 10 VDC, COG, SMD, MLCC, Ultra-Stable, Low Loss, Class I, 0201

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General Information SMD Comm COG Series Style SMD Chip Description SMD, MLCC, Ultra-Stable, Low Loss, Class I Features Ultra-Stable, Low Loss, Class I RoHS Yes Termination Tin

Specifications	
Capacitance	27 pF
Measurement Condition	1 MHz 1.0Vrms
Tolerance	10%
Voltage DC	10 VDC
Dielectric Withstanding Voltage	25 VDC
Temperature Range	-55/+125°C
Temp. Coefficient	COG
Capacitance Change with Reference to +25°C and 0 VDC Applied (TCC)	30 ppm/C, 1MegaHz 1.0Vrms
Dissipation Factor	0.1% 1 MHz 1.0Vrms
Aging Rate	0% Loss/Decade Hour
Insulation Resistance	100 GOhms

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

Dimensions

Packaging Specifications

Packaging Quantity

Chip Size

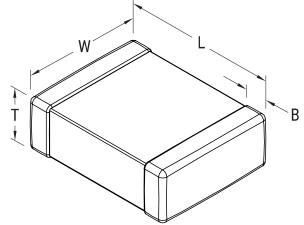
Packaging

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the 3D model.	Marking	No
	AEC-Q200	No
	Typical Component Weight	0.32 mg
	Shelf Life	78 Weeks
	MSL	1
	Specifications	
0201	Capacitance	27 pF
0.6mm +/-0.03mm	Measurement Condition	1 MHz 1.0Vrms
0.3mm +/-0.03mm	Tolerance	10%
0.3mm +/-0.03mm	Voltage DC	10 VDC
0.15mm +/-0.05mm	Dielectric Withstanding Voltage	25 VDC
	Temperature Range	-55/+125°C
	Temp. Coefficient	COG
T&R, 180mm, Paper Tape	Capacitance Change with Reference to $+25^{\circ}$ C and $0.$ VDC	30 ppm/C, 1Me



Click here for the 3D model.

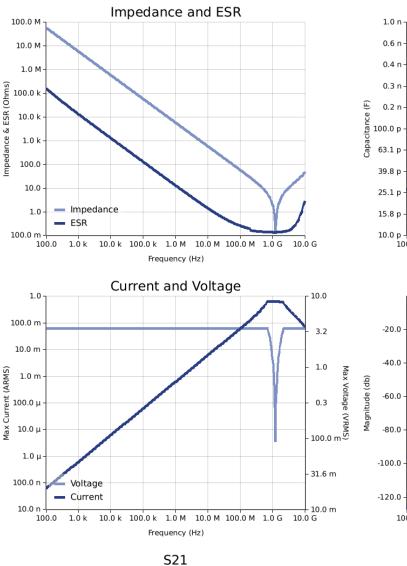
15000

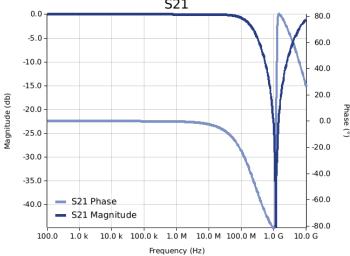


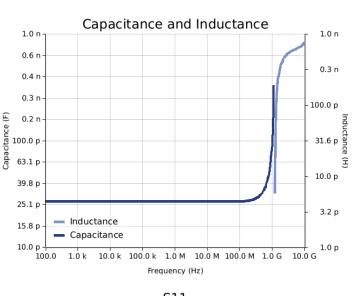
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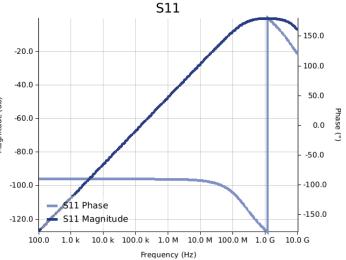
Simulations

For the complete simulation environment please visit K-SIM.











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These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR used for hipple klipple current younge vs. requericy plots is the ESR at an bient temperature.
 The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
 The effects shown herein are based on measured data from a multiple part sample of the parts in question.
 Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.
 The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages and the part of the parts of the part of the
- generated at any other harmonics. Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

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If you have any questions please contact K-SIM.